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Correction

Correction: He et al. A 3.95 ppm/°C 7.5 µW Second-Order Curvature Compensated Bandgap Reference in 0.11 µm CMOS. *Electronics* 2022, *11*, 2869

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Additional Affiliation

In the published publication [1], there was an error regarding the affiliation of Yuefeng He, Guoshun Yuan, Lei Lei, Hongjiang Yu and Dewei Kong. In addition to affiliation 2, the updated affiliation should include: University of Chinese Academy of Sciences, Beijing 100049, China. The authors state that the scientific conclusions are unaffected. This correction was approved by the Academic Editor. The original publication has also been updated.

Reference

1. He, Y.; Yuan, G.; Lei, L.; Yu, H.; Kong, D. A 3.95 ppm/°C 7.5 µW Second-Order Curvature Compensated Bandgap Reference in 0.11 µm CMOS. *Electronics* **2022**, *11*, 2869. [CrossRef]

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